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Coordenadores

Prof. Dr. Osvaldo Novais de Oliveira Junior

Diretor do Instituto de Física de São Carlos – Universidade de São Paulo

Prof. Dr. Javier Alcides Ellena

Presidente da Comissão de Pós Graduação do Instituto de Física de São Carlos – Universidade de São Paulo

Profa. Dra. Tereza Cristina da Rocha Mendes

Presidente da Comissão de Graduação do Instituto de Física de São Carlos – Universidade de São Paulo

Comissão Organizadora

Adonai Hilario

Arthur Deponte Zutião

Elisa Goettems

Gabriel dos Santos Araujo Pinto

Henrique Castro Rodrigues

Jeffer Santiago Mares

João Victor Pimenta

Julia Martins Simão

Letícia Martinelli

Lorany Vitoria dos Santos Barbosa

Lucas Rafael Oliveira Santos Eugênio

Natasha Mezzacappo

Paulina Ferreira

Vinícius Pereira Pinto

Willian dos Santos Ribela

Normalização e revisão – SBI/IFSC

Ana Mara Marques da Cunha Prado

Maria Cristina Cavarette Dziabas

Maria Neusa de Aguiar Azevedo

Sabrina di Salvo Mastrantonio

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Inkjet-printed complementary inverters based on Organic Electrochemical Transistors

LUGINIESKI, Marcos; FARIA, Gregório

mluginieski@ifsc.usp.br

Inkjet-printed complementary inverters based on Organic Electrochemical Transistors (OECT) are the device of choice for building logical, sophisticated and smart electronic devices. Typically, a complementary inverter comprises a n-type and a p-type transistor. While p-type organic transistors are already well established in the literature, n-type devices still face a lack of publications and studies due to its poor stability and electronic conductivity. (1) Therefore, to achieve logical, sophisticated and smart devices, these challenges must be overcome. Among them, this project will investigate the mechanisms of operation of these devices, the physics of the interfaces involved, stability and optimization. Particularly, the OECTs operation is based on electrochemical doping of the organic semiconductor by ionic species coming from electrolyte. The volumetric capacitance (C^*) is the fundamental physical parameter that gives information about this phenomenon. Usually, C^* is extracted with Electrochemical Impedance Spectroscopy (EIS) in a capacitor-like structure. Recent studies, however, have reported a pulsed voltage technique for calculating impedances parameter, directly from the transistor structure (three terminal device). (2) Therefore, the first goal of this project is to confront these two correlated, yet, completely different techniques for characterizing OECTs. The materials choice for the OECTs here in explored are: P3HT, PBTTT, PTB7-Th and PEDOT:PSS as p-type and P (NDI2OD-T2) and NDI-2Tz as n-type organic semiconductors. As for the electrolytes, standard aqueous 100 mM KCl solution shall be used. This topic is quite recent in the literature and, therefore, its study constitutes opportunities to contribute to the understanding of fundamental aspects of the area, as well as the possibility of publications with high scientific and technological impact.

Palavras-chave: Organic electrochemical transistors. Volumetric capacitance. Electrochemical impedance spectroscopy.

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Referências:

- 1 SUN, H.; GERASIMOV, J.; BERGGREN, M.; FABIANO, S. N-Type organic electrochemical transistors: materials and challenges. **Journal Of Materials Chemistry C**, v. 6, n. 44, p. 11778-11784, 2018.
- 2 FARIA, G. C.; DUONG, D. T.; SALLEO, A. On the transient response of organic electrochemical transistors. **Organic Electronics**, v. 45, p. 215-221, June 2017.